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# SmartLEWIS™ RX+ TDA5240

Enhanced Sensitivity Multi-Channel  
Quad-Configuration Receiver  
with Digital Baseband Processing

Wireless Control



Never stop thinking.

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## TDA5240

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Page	Subjects (major changes since last revision)
Page 27	Update of Figure 9
Page 29	Update of Figure 10
Page 31	AFC limitation added
Page 33	AGC setting proposal added
Page 34	New Section 2.4.6.5 ADC added
Page 36	Additional information on RSSIPRX register inserted
Page 41	Signal and Noise Detector Procedure adapted
Page 45	x_CDRRI register recommendation changed
Page 49, 52, 56	Data Slicer Modes adapted; limitation added
Page 69	Update of Figure 41
Page 70	Update of Figure 42
Page 78	Additional hint on clock and data recovery algorithm of the user software inserted
Page 84	PLDLEN limitation added
Page 86	Limitation for ISx readout and Burst-read function added
Page 88	Limitation for Burst-read function added
Page 107	Description of "Parallel Wake-up Search" adapted
Page 125	Additional hints added
Page 127	Adaption of Section 4.1
Page 130	New item C7 added
Page 138 f	Comments added for items I6, I7, I8, I9, J11, J12
Page 138	Item J1 updated
Page 141 ff	General test conditions noted for parameters K, L and M
Page 147	BOM components C7, C8, L1, R2 and R3 updated

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# 1 Product Description

## 1.1 Overview

The IC is a low power ASK/FSK Receiver for the frequency bands 300-320, 425-450, 863-870 and 902-928 MHz. Bi-phase modulation schemes, like Manchester, bi-phase mark, bi-phase space and differential Manchester are supported.

The chip offers best-in-class sensitivity performance at a very high level of integration and needs only a few external components.

The device is qualified to automotive quality standards and operates between -40 and +105°C at supply voltage ranges of 3.0-3.6 Volts or 4.5-5.5 Volts.

The receiver is realized as a double down conversion super-heterodyne/low-IF architecture each with image rejection supplemented by digital signal processing in the baseband. A fully integrated Sigma-Delta Fractional-N PLL Synthesizer allows for high-resolution frequency generation and uses a crystal oscillator as the reference. The on-chip temperature sensor may be utilized for temperature drift compensation via the crystal oscillator.

The digital baseband processing unit together with the high performance down converter is the key element for the exceptional sensitivity performance of the device which take it close to the theoretical top-performance limits. It comprises signal and noise detectors, matched data filter, clock and data recovery, data slicer and a format decoder. It demodulates the received ASK or FSK data stream independently and recovers the data clock out of the received data stream with very fast synchronization times which can then be either accessed via separate pins or used for further processing like frame synchronization and intermediate storage in the on-chip FIFO. The RSSI output signal is converted to the digital domain with an ADC. All these signals are accessible via the 4-wire SPI interface bus. Up to 4 pre-configured telegram formats can be stored into the device offering independent pre-processing of the received data to an extent not available till now. The down converter can be also configured in single-conversion mode at moderately reduced selectivity performance but at the advantage of omitting the IF ceramic filter.



## 1.2 Features

- Enhanced sensitivity receiver
- Multi-band/Multi-Channel (300-320, 425-450, 863-870 and 902-928 MHz)
- One crystal frequency for all supported frequency bands
- 21-bit Sigma-Delta Fractional-N PLL synthesizer with high resolution of 10.5 Hz
- Up to 4 parallel parameter sets for autonomous scanning and receiving from different sources reduces significantly host processor power consumption and system standby power consumption
- Up to 12 different frequency channels are supported with 10.5 Hz resolution each
- Autonomous receive mode leads to reduced noise of host processor and improved system performance
- Ultrafast Wake-up on RSSI
- Fast synchronization on incoming data stream typically within first 4 bits of a telegram
- Selectable IF filter bandwidth and optional external filters possible
- Double down conversion image reject mixer
- ASK and FSK capability
- Automatic Frequency Control (AFC) for carrier frequency offset compensation
- Supports bi-phase line codes like Manchester, bi-phase mark/space and differential Manchester
- NRZ data pre-processing capability
- Digital base band receiver with clock synch, frame synch, format decoding and FIFO
- Separate outputs for recovered data and clock
- RSSI peak detectors
- Wake-up generator and polling timer unit
- Message ID scanning
- Unique 32-bit serial number
- On-chip temperature sensor
- Integrated timer usable for external watch unit
- Integrated 4-wire SPI interface bus
- Supply voltage range 3.0 Volts to 3.6 Volts or 4.5 Volts to 5.5 Volts
- Operating temperature range -40 to +105°C
- ESD protection +/- 2 kV on all pins
- Package PG-TSSOP-28

## 1.3 Applications

- Remote keyless entry systems
- Remote start applications
- Tire pressure monitoring
- Short range radio data transmission
- Remote control units
- Cordless alarm systems
- Remote metering

## 2 Functional Description

### 2.1 Pin Configuration

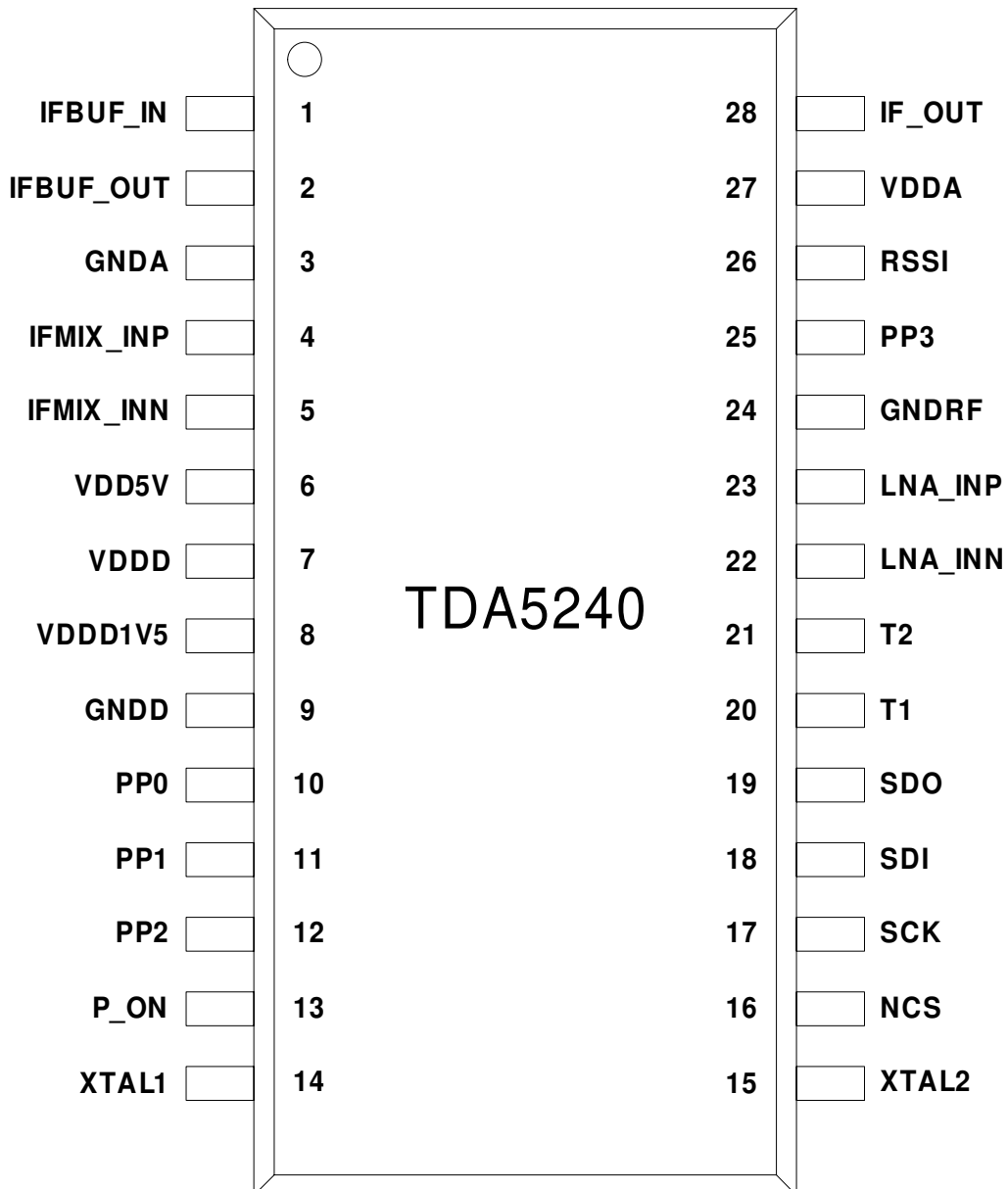
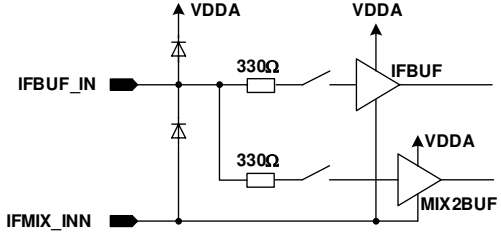
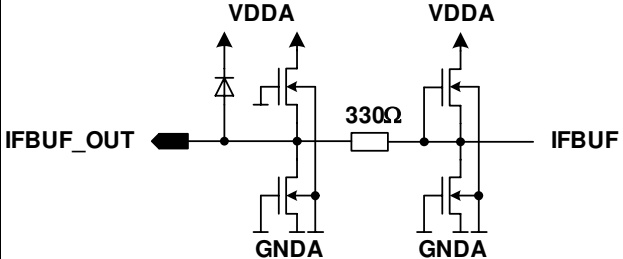
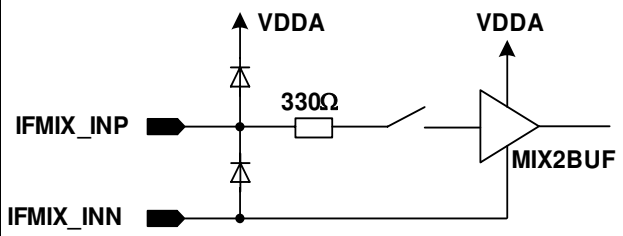


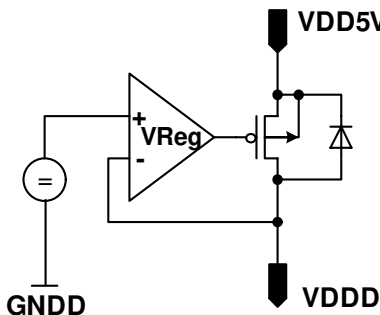
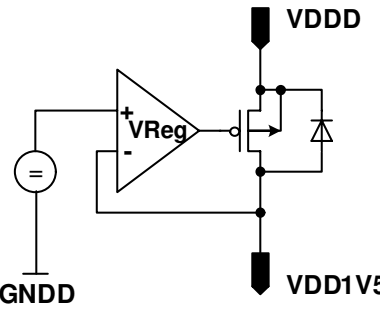
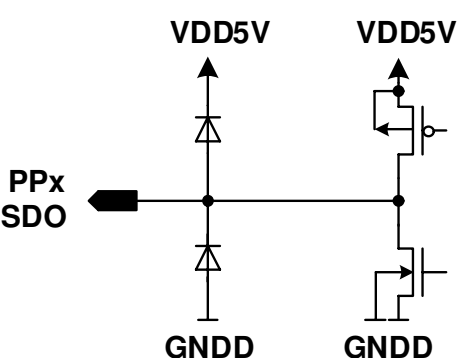
Figure 1 Pin-out

## 2.2 Pin Definition and Pin Functionality

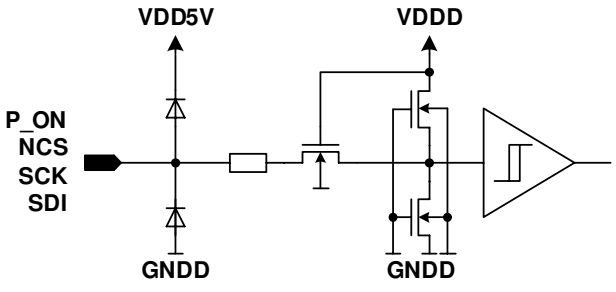
Table 1 Pin Definition and Function

Pin No.	Pad name	Equivalent I/O Schematic	Function
1	IFBUF_IN		<p>Analog input IF Buffer input</p> <p>Note: Input is biased at <math>VDDA/2</math></p>
2	IFBUF_OUT		<p>Analog output IF Buffer output</p>
3	GND_A		Analog ground
4	IFMIX_INP		<p>Analog input + IF mixer input</p> <p>Note: Input is biased at <math>VDDA/2</math></p>
5	IFMIX_INN	see schematic of Pin 1 and 4	Analog input. - IF mixer input
6	VDD5V		Analog input 5 Volt supply input

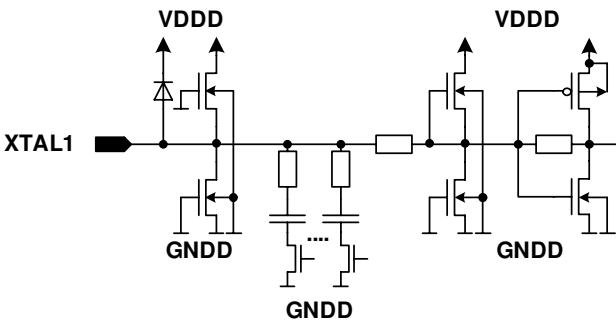
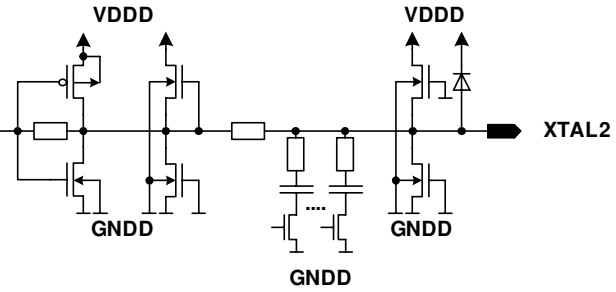
Functional Description

Pin No.	Pad name	Equivalent I/O Schematic	Function
7	VDDD		Analog input digital supply input
8	VDDD1V5		Analog output 1.5 Volt voltage regulator
9	GNDD		Digital ground
10	PP0		Digital output CLK_OUT, RX_RUN, NINT, LOW, HIGH, DATA, DATA_MATCHFIL, CH_DATA, CH_STR, RXD and RXSTR are programmable via a SFR (Special Function Register), default = CLK_OUT

Functional Description

Pin No.	Pad name	Equivalent I/O Schematic	Function
11	PP1	see schematic of Pin 10	Digital output CLK_OUT, RX_RUN, NINT, LOW, HIGH, DATA, DATA_MATCHFIL, CH_DATA, CH_STR, RXD and RXSTR are programmable via a SFR, default = DATA
12	PP2	see schematic of Pin 10	Digital output CLK_OUT, RX_RUN, NINT, LOW, HIGH, DATA, DATA_MATCHFIL, CH_DATA, CH_STR, RXD and RXSTR are programmable via a SFR, default = NINT
13	P_ON		Digital input power-on reset

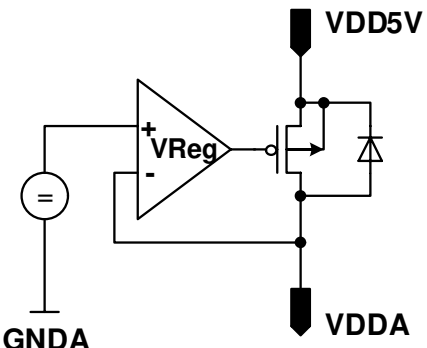
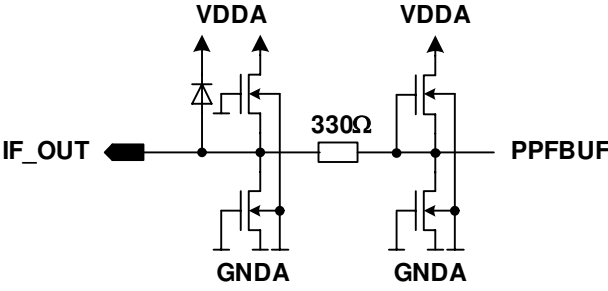
Functional Description

Pin No.	Pad name	Equivalent I/O Schematic	Function
14	XTAL1		Analog input crystal oscillator input
15	XTAL2		Analog output crystal oscillator output
16	NCS	see schematic of Pin 13	Digital input SPI enable
17	SCK	see schematic of Pin 13	Digital input SPI clock
18	SDI	see schematic of Pin 13	Digital input SPI data in
19	SDO	see schematic of Pin 10	Digital output SPI data out
20	T1		Digital input, connect to Digital Ground
21	T2		Digital input, connect to Digital Ground

Functional Description

Pin No.	Pad name	Equivalent I/O Schematic	Function
22	LNA_INN		Analog input - RF input
23	LNA_INP		Analog input + RF input
24	GNDRF		RF analog ground
25	PP3	see schematic of Pin 10	Digital output RX_RUN, NINT, LOW, HIGH, DATA, DATA_MATCHFIL, CH_DATA, CH_STR, RXD and RXSTR are programmable via a SFR, default = RX_RUN
26	RSSI		Analog output analog RSSI output/ analog test pin ANA_TST

Functional Description

Pin No.	Pad name	Equivalent I/O Schematic	Function
27	VDDA	 <p>The schematic shows a voltage regulator block labeled 'VReg'. The non-inverting input (+) is connected to a terminal labeled 'VDD5V'. The inverting input (-) is connected to a terminal labeled 'VDDA'. The output of the regulator is connected to a PMOS transistor. The gate of this PMOS transistor is also connected to the 'VDDA' terminal. The source of the PMOS transistor is connected to 'VDD5V' and the drain is connected to the 'VDDA' terminal. A diode is connected in parallel with the PMOS transistor, with its anode to 'VDD5V' and its cathode to 'VDDA'.</p>	Analog input Analog supply
28	IF_OUT	 <p>The schematic shows a push-pull output stage. It consists of two PMOS transistors and two NMOS transistors. The gates of the PMOS transistors are connected to 'VDDA' and the gates of the NMOS transistors are connected to 'GND'. The sources of all transistors are connected to 'GND'. The drains of the PMOS transistors are connected to 'VDDA'. The drains of the NMOS transistors are connected to a node labeled 'PPFBUF'. A resistor with a value of 330Ω is connected between 'PPFBUF' and the 'IF_OUT' terminal.</p>	Analog output IF output



2.3 Functional Block Diagram

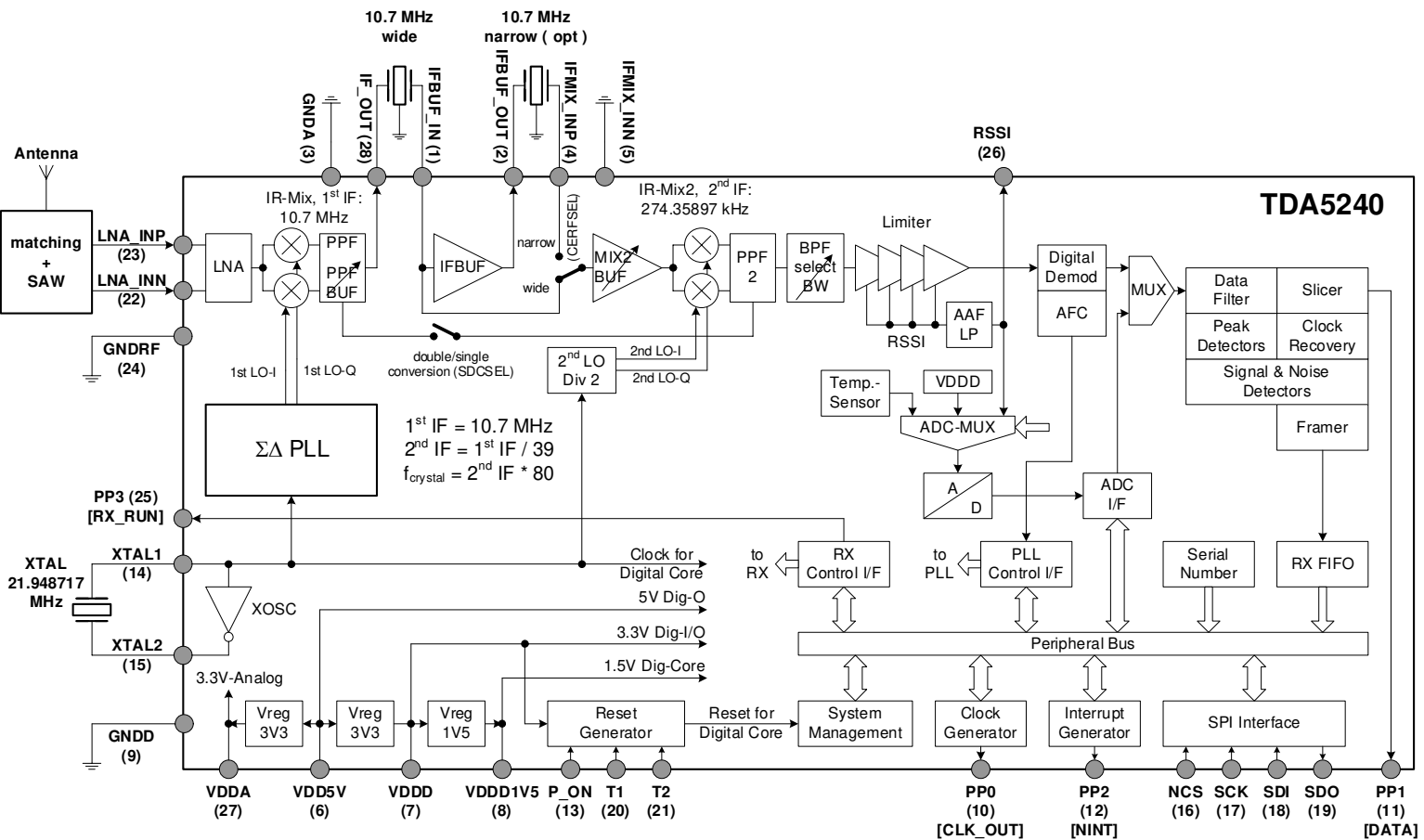


Figure 2 TDA5240 Block Diagram <sup>1)</sup>

<sup>1)</sup> The function on each PpX port pin can be programmed via SFR (see also Table 1). Default values are given in squared brackets in Figure 2.

## 2.4 Functional Block Description

### 2.4.1 Architecture Overview

A fully integrated Sigma-Delta Fractional-N PLL Synthesizer covers the frequency bands 300-320 MHz, 425-450 MHz, 863-870 MHz, 902-928 MHz with a high frequency resolution, using only one VCO running at around 3.6 GHz. This makes the IC most suitable for Multi-Band/Multi-Channel applications.

For Multi-Channel applications a very good channel separation is essential. To achieve the necessary high sensitivity and selectivity a double down conversion super-heterodyne architecture is used. The first IF frequency is located around 10.7 MHz and the second IF frequency around 274 kHz. For both IF frequencies an adjustment-free image frequency rejection feature is realized. In the second IF domain the filtering is done with an on-chip third order bandpass polyphase filter. A multi-stage bandpass limiter completes the RF/IF path of the receiver. For Single-Channel applications with relaxed requirements to selectivity, a single down conversion low-IF scheme can be selected.

For Multi-Channel systems where even higher channel separation is required, up to two (switchable) external ceramic (CER) filters can be used to improve the selectivity.

An RSSI generator delivers a DC signal proportional to the applied input power and is also used as an ASK demodulator. Via an anti-aliasing filter this signal feeds an ADC with 10 bits resolution.

The harmonic suppressed limiter output signal feeds a digital FSK demodulator. This block demodulates the FSK data and delivers an AFC signal which controls the divider factor of the PLL synthesizer.

A digital receiver, which comprises RSSI peak detectors, a matched data filter, a clock and data recovery, a data slicer, a frame synchronization and a data FIFO, decodes the received ASK or FSK data stream. The recovered data and clock signals are accessible via 2 separate pins. The FIFO data buffer is accessible via the SPI bus interface.

The crystal oscillator serves as the reference frequency for the PLL phase detector, the clock signal of the Sigma-Delta modulator and divided by two as the 2<sup>nd</sup> local oscillator signal. To accelerate the start up time of the crystal oscillator two modes are selectable: a Low Power Mode (with lower precision) and a High Precision Mode.

## 2.4.2 Block Overview

The TDA5240 is separated into the following main blocks:

- **RF / IF Receiver**
- **Crystal Oscillator and Clock Divider**
- **Sigma-Delta Fractional-N PLL Synthesizer**
- **ASK / FSK Demodulator incl. AFC, AGC and ADC**
- **RSSI Peak Detector**
- **Digital Baseband Receiver**
- **Power Supply Circuitry**
- **System Interface**
- **System Management Unit**

## 2.4.3 RF/IF Receiver

The receiver path uses a double down conversion super-heterodyne/low-IF architecture, where the first IF frequency is located around 10.7 MHz and the second IF frequency around 274 kHz. For the first IF frequency an adjustment-free image frequency rejection is realized by means of two low-side injected I/Q-mixers followed by a second order passive polyphase filter centered at 10.7 MHz (PPF). The I/Q-oscillator signals for the first down conversion are delivered from the PLL synthesizer. The frequency selection in the first IF domain is done by an external CER filter (optionally by two, decoupled by a buffer amplifier). For moderate or low cost applications, this ceramic filter can be substituted by a simple LC Pi-filter or completely by-passed using the receiver as a single down conversion low-IF scheme with 274 kHz IF frequency. The down conversion to the second IF frequency is done by means of two high-side injected I/Q-mixers together with an on-chip third order bandpass polyphase filter (PPF2 + BPF). The I/Q-oscillator signals for the second down conversion are directly derived by division of two from the crystal oscillator frequency. The bandwidth of the bandpass filter (BPF) can be selected from 50 kHz to 300 kHz in 5 steps. For a frequency offset of -150 kHz to -120 kHz, the AFC (Automatic Frequency Control) function is mandatory. Activated AFC option might require a longer preamble sequence in the receive data stream.

The receiver enable signal (RX\_RUN) can be offered at each of the port pins to control external components. Whenever the receiver is active, the RX\_RUN output signal is active. Active high or active low is configurable via PPCFG2 register.

Functional Description

The frequency relations are calculated with the following formulas:

$$f_{IF1} = 10.7\text{MHz}$$

$$f_{IF2} = \frac{f_{IF1}}{39}$$

$$f_{\text{crystal}} = f_{IF2} \times 80$$

$$f_{LO2} = \frac{f_{\text{crystal}}}{2}$$

$$f_{LO1} = f_{\text{crystal}} \times \text{NF}_{\text{divider}}$$

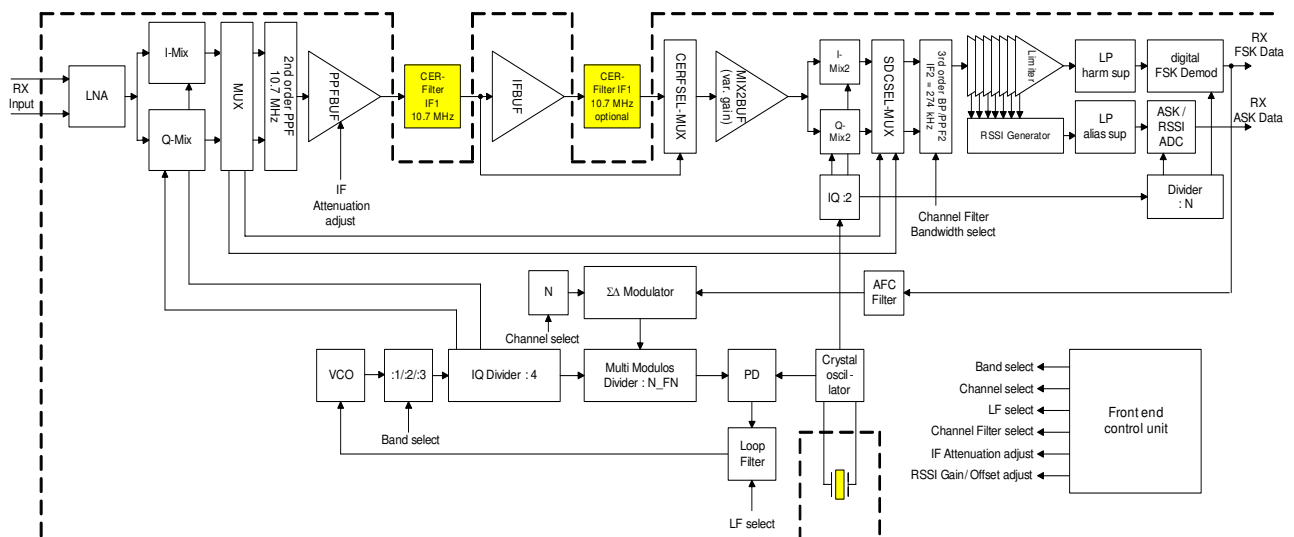


Figure 3 Block Diagram RF Section

The front end of the receiver comprises an LNA, an image reject mixer and a digitally gain controlled buffer amplifier. This buffer amplifier allows the production spread of the on-chip signal strip, of external matching circuitry and RF SAW and ceramic IF filters to be trimmed. The second image reject mixer down converts the first IF to the second IF.

Functional Description

The bandpass filter follows the subsequent formula:

$$f_{\text{center}} = \sqrt{f_{\text{corner, low}} \times f_{\text{corner, high}}}$$

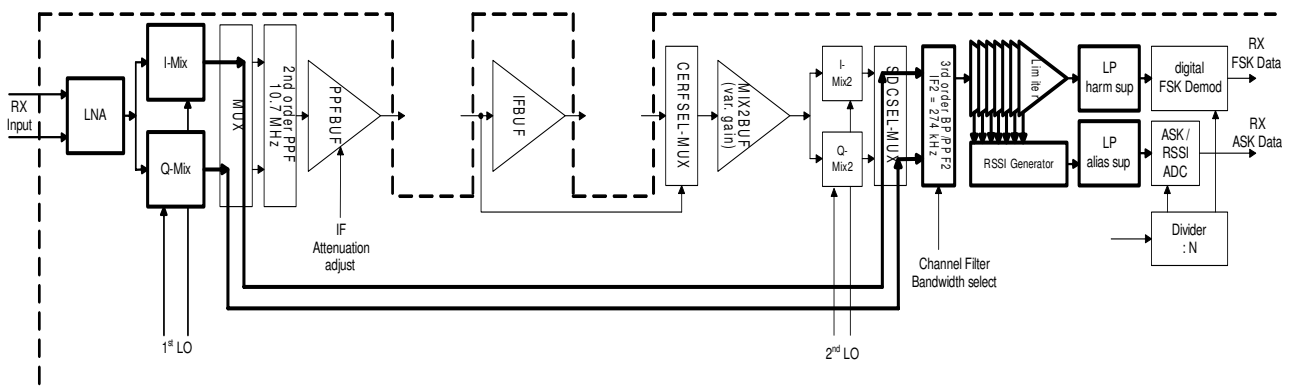
Therefore asymmetric corner frequencies can be observed. The use of AFC results in more symmetry.

A multi-stage bandpass limiter at a center frequency of 274 kHz completes the receiver chain. The -3dB corner frequencies of the bandpass limiter are typically at 75 kHz and at 520 kHz.

An RSSI generator delivers a DC signal proportional to the applied input power and is also used as an ASK demodulator. Via a programmable anti-aliasing filter this signal is converted to the digital domain by means of a 10-bit ADC.

The limiter output signal is connected to a digital FSK demodulator.

The immunity against strong interference frequencies (so called blockers) is determined by the available filter bandwidth, the filter order and the 3<sup>rd</sup> order intercept point of the front end stages. For Single-Channel applications with moderate requirements to the selectivity the performance of the on-chip 3<sup>rd</sup> order bandpass polyphase filter might be sufficient. In this case no external filters are necessary and a single down conversion architecture can be used, which converts the input signal frequency directly to the 2<sup>nd</sup> IF frequency of 274 kHz.



**Figure 4 Single Down Conversion (SDC, no external filters required)**

For Multi-Channel applications or systems which demand higher selectivity the double down conversion scheme together with one or two external CER filters can be selected. The order of such ceramic filters is in a range of 3, so the selectivity is further improved and a better channel separation is guaranteed.

Functional Description

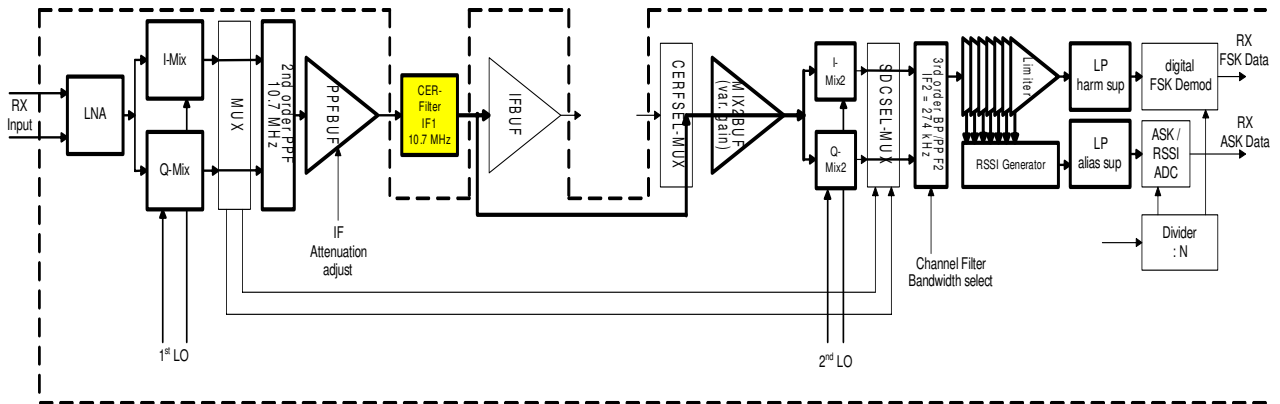


Figure 5 Double Down Conversion (DDC) with one external filter

For applications which demand very high selectivity and/or channel separation even two CER filters may be used. Also in applications where one channel requires a wider bandwidth than the other (e.g. TPMS and RKE) the second filter can be by-passed.

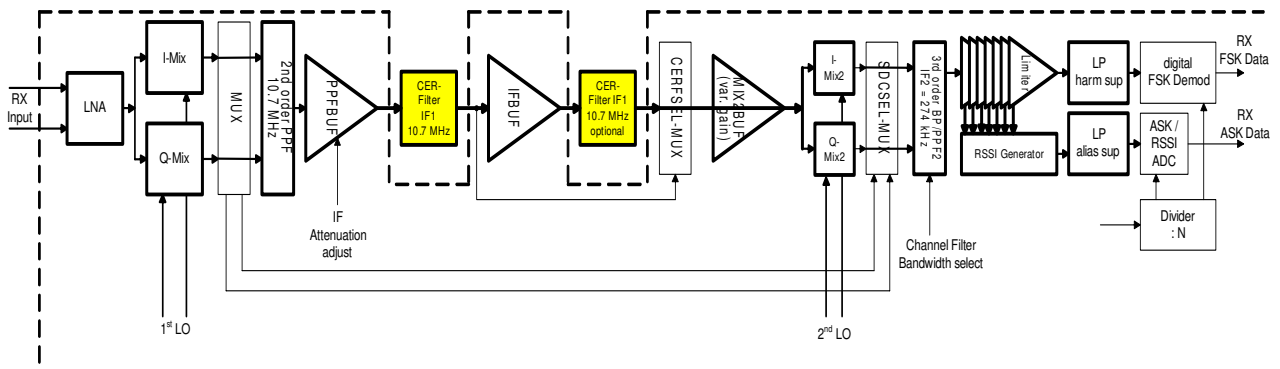


Figure 6 Double Down Conversion (DDC) with two external filters

### 2.4.4 Crystal Oscillator and Clock Divider

The crystal oscillator is a Pierce type oscillator which operates together with the crystal in parallel resonance mode. An automatic amplitude regulation circuitry allows the oscillator to operate with minimum current consumption. In SLEEP Mode, where the current consumption should be as low as possible, the load capacitor must be small and the frequency is slightly detuned, therefore all internal trim capacitors are disconnected. The internal capacitors are controlled by the crystal oscillator calibration registers XTALCALx. With a binary weighted capacitor array the necessary load capacitor can be selected.

Whenever a XTALCALx register value is updated, the selected trim capacitors are automatically connected to the crystal so that the frequency is precise at the desired value. The SFR control bit XTALHPMS can be used to activate the High Precision Mode also during SLEEP Mode.

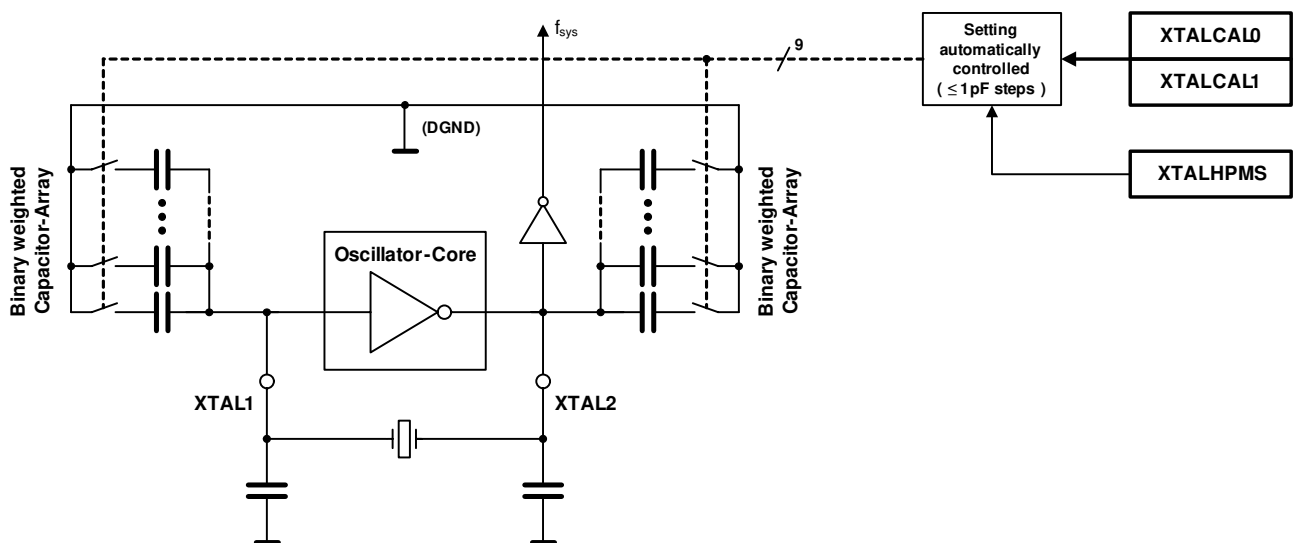


Figure 7 Crystal Oscillator

### Recommended Trimming Procedure

- Set the registers XTALCAL0 and XTALCAL1 to the expected nominal values
- Set the TDA5240 to Run Mode Slave
- Wait for 0.5ms minimum
- Trim the oscillator by increasing and decreasing the values of XTALCAL0/1
- Register changes larger than 1 pF are automatically handled by the TDA5240 in 1pF steps
- After the Oscillator is trimmed, the TDA5240 can be set to SLEEP mode and keeps these values during SLEEP mode
- Add the settings of XTALCAL0/1 to the configuration. It must be set after every power up or brownout!

### Using the High Precision Mode

As discussed earlier, the TDA5240 allows the crystal oscillator to be trimmed by the use of internal trim capacitors. It is also possible to use the trim functionality to compensate temperature drift of crystals.

During Run Mode (always when the receiver is active) the capacitors are automatically connected and the oscillator is working in the High Precision Mode.

On entering SLEEP Mode, the capacitors are automatically disconnected to save power.

If the High Precision Mode is also required for SLEEP Mode, the automatic disconnection of trim capacitors can be avoided by setting XTALHPMS to 1 (enable XTAL High Precision Mode during SLEEP Mode).

### External Clock Generation Unit

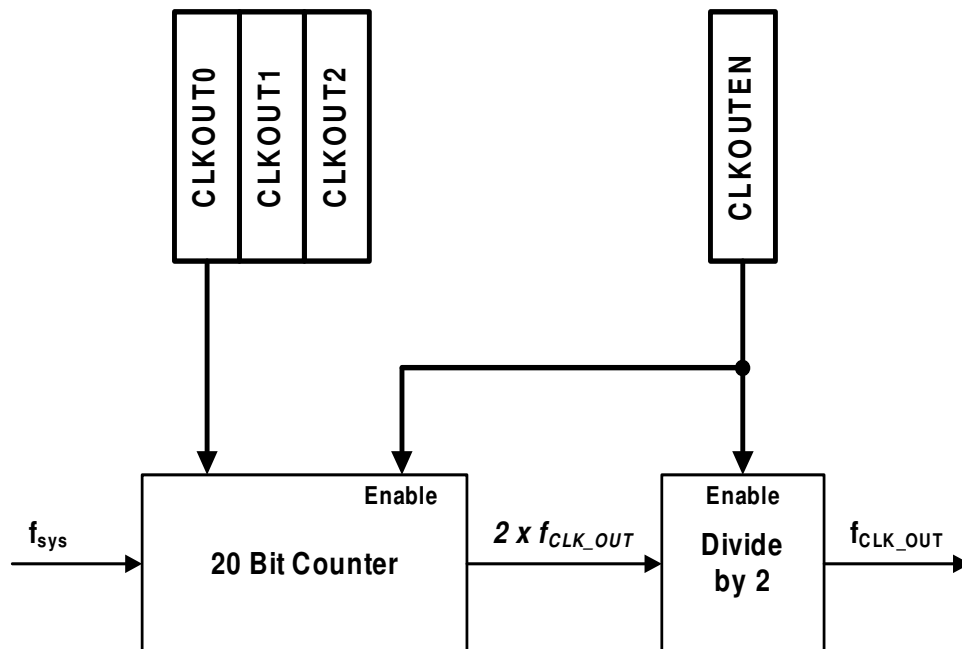
A built in programmable frequency divider can be used to generate an external clock source out of the crystal reference. The 20 bit wide division factor is stored in the registers CLKOUT0, CLKOUT1 and CLKOUT2. The minimum value of the programmable frequency divider is 2. This programmable divider is followed by an additional divider by 2, which generates a 50% duty cycle of the CLK\_OUT signal. So the maximum frequency at the CLK\_OUT signal is the crystal frequency divided by 4. The minimum CLK\_OUT frequency is the crystal frequency divided by  $2^{21}$ .

To save power, this programmable clock signal can be disabled by the SFR control bit CLKOUTEN. In this case the external clock signal is set to low.



The resulting CLK\_OUT frequency can be calculated by:

$$f_{\text{CLKOUT}} = \frac{f_{\text{sys}}}{2 \cdot \text{divisionfactor}}$$



**Figure 8 External Clock Generation Unit**

The maximum CLK\_OUT frequency is limited by the driver capability of the PPx pin and depends on the external load connected to this pin. Please be aware that large loads and/or high clock frequencies at this pin may interfere with the receiver and reduce performance.

After Reset the PPx pin is activated and the division factor is initialized to 11 (equals  $f_{\text{CLK\_OUT}} = 998 \text{ kHz}$ ).

A clock output frequency higher than 1 MHz is not supported.

For high sensitivity applications, the use of the external clock generation unit is not recommended.

### 2.4.5 Sigma-Delta Fractional-N PLL Block

The Sigma-Delta Fractional-N PLL is fully integrated on chip. The **Voltage Controlled Oscillator (VCO)** with on-chip LC-tank runs at approximately 3.6 GHz and is first divided with a band select divider by 1, 2 or 3 and then with an I/Q-divider by 4 which provides an orthogonal local oscillator signal for the first image reject mixer with the necessary high accuracy.

The multi-modulus divider determines the channel selection and is controlled by a 3<sup>rd</sup> order Sigma-Delta Modulator (*SDM*). A type IV phase detector, a charge pump with programmable current and an on-chip loop filter closes the phase locked loop.

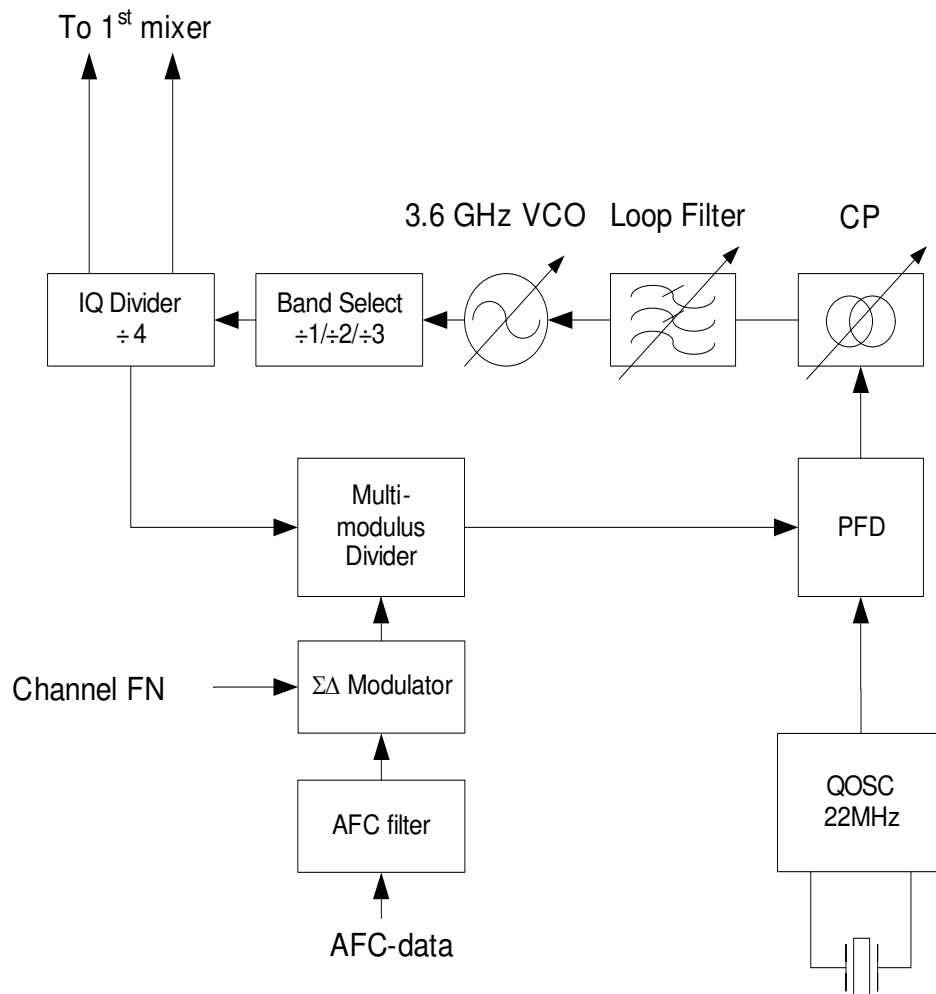


Figure 9 Synthesizer Block Diagram